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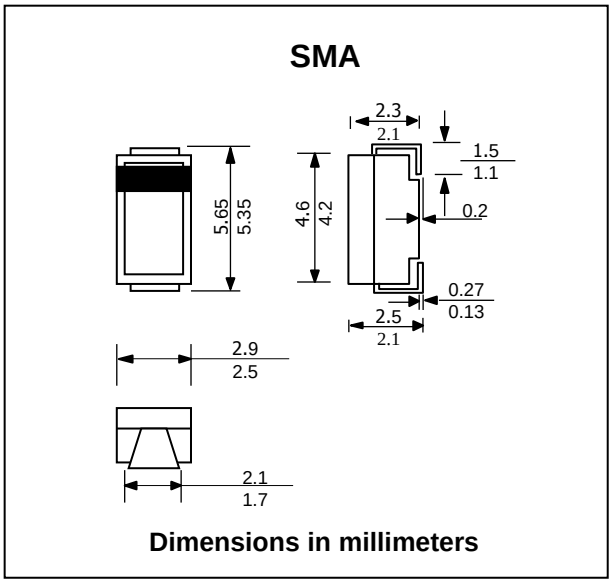
SR1N - SR1P

SURFACE MOUNT FAST RECOVERY RECTIFIER

PRV : 1200 ~ 1600 Volts
Io : 1.0 Ampere



FEATURES :

* Glass passivated junction chip
* High surge current capability
* High reliability
* Low reverse current
* Fast recovery time
* Pb Free / RoHS Compliant

MECHANICAL DATA :

* Case : SMA Molded plastic
* Epoxy : UL94V-O rate flame retardant
* Polarity : Color band denotes cathode end
* Mounting position : Any
* Weight : 0.060 gram (Approximately)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.

RATING	SYMBOL	SR1N	SR1O	SR1P	UNIT
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	1200	1400	1600	V
Maximum RMS Voltage	V_{RMS}	840	980	1120	V
Maximum DC Blocking Voltage	V_{DC}	1200	1400	1600	V
Maximum Average Forward Current Ta = 75°C at 8.3 ms Single Half sine-wave	$I_{F(AV)}$	1.0			A
Maximum Non-Repetitive Peak Forward Surge Current	I_{FSM}	30			A
Maximum Peak Forward Voltage at I_F = 1.0 A	V_F	2.6			V
Maximum DC Reverse Current T_a = 25 °C	I_R	5.0			µA
at Rated DC Blocking Voltage T_a = 100 °C	$I_{R(H)}$	50			µA
Reverse Recovery Time (Note 1)	Trr	300			ns
Operating Junction Temperature Range	T_J	- 40 to + 150			°C
Storage Temperature Range	T_{STG}	- 40 to + 150			°C

Note :

(1) Reverse Recovery Test Conditions : I_F = 0.5 A, I_R = 1.0 A, Irr = 0.25 A.

RATING AND CHARACTERISTIC CURVES (SR1N - SR1P)

FIG. 1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

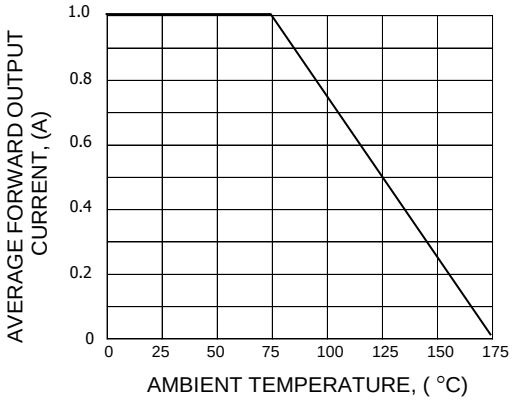


FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

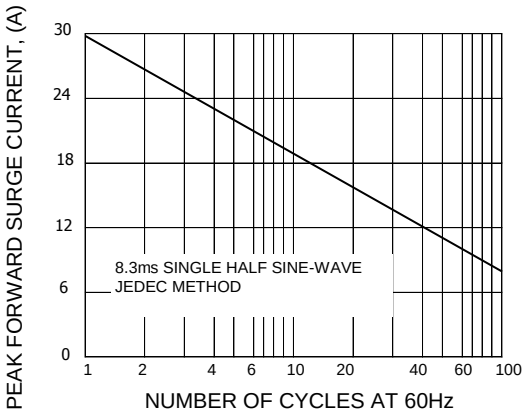


FIG. 3 - TYPICAL FORWARD CHARACTERISTICS

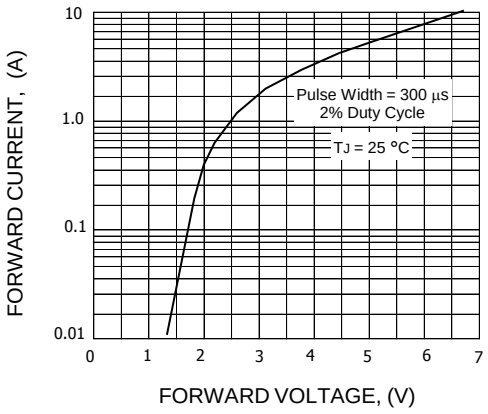


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS